

**IN THE SPECIFICATION**

Please amend paragraph [0051] as follows:

That is, as shown in Fig. 4 showing the explanation plan view of a partial of the gate wiring 2 formed on the most outer portion and the source wiring 3, connecting portion 3a for connecting the source wiring 3 and the most internal layer of the protective diode 1 and connecting portion 2a for connecting each gate electrodes of the cells and the gate wiring 2 are formed alternately in plan view, as shown in Fig. 4, they are formed in patterns of combs, which teeth are engaged each other. With thanks of this, the gate electrode pad can be connected to the most external cells in the cell group thorough the metal film.